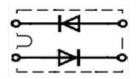




# **Ultrafast High Voltage Diode**

#### **FEATURES**

- · High surge current capability
- · Wide current range
- High voltage ratings up to 1200V
- Minimum Lot-to-Lot variations for robust device performance and reliable operation



#### **APPLICATIONS**

 Be suitable in motor control circuitries, or in the primary of SMPS as snubber, clamping or demagnetizing diodes. They are also suitable for secondary of SMPS as high voltage rectifier diodes.



#### **ABSOLUTE MAXIMUM RATINGS**

isc website: www.iscsemi.cn

SYMBOL	PARAMETER	CONDITIONS		VALUE	UNIT
V <sub>RRM</sub>	Repetitive Peak Reverse Voltage			1200	V
I <sub>F(AV)</sub>	Average Forward Current			2*45	A
I <sub>FRMS</sub>	RMS Forward Current	$T_{VJ} = T_{VJM}$		70	А
	Surge Forward Current	t=10ms(50Hz),sine	- T <sub>VJ</sub> =45℃	200	- A
		t=8.3ms(60Hz),sine		210	
I <sub>FSM</sub>		t=10ms(50Hz),sine	T <sub>VJ</sub> =150℃	185	
		t=8.3ms(60Hz),sine		195	
	I <sup>2</sup> t for fusing	t=10ms(50Hz),sine	- T <sub>VJ</sub> =45°C	200	- KA <sub>2</sub> s
l²t		t=8.3ms(60Hz),sine		180	
		t=10ms(50Hz),sine	T 450%	170	
		t=8.3ms(60Hz),sine	- T <sub>VJ</sub> =150℃	160	
TJ	Junction Temperature			-40~150	°C
T <sub>stg</sub>	Storage Temperature Range			-40~150	°C

1 isc & iscsemi is registered trademark



## **STTA9012TV2**

# **Ultrafast High Voltage Diode**

#### THERMAL CHARACTERISTICS

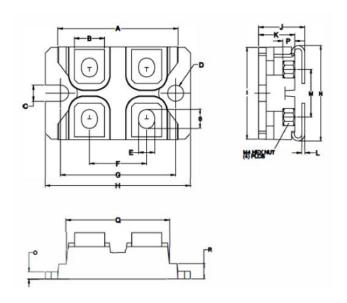
SYMBOL	PARAMETER	MAX	UNIT
R <sub>th j-c</sub>	Thermal Resistance, Junction to Case		°C/W

#### **ELECTRICAL CHARACTERISTICS**

SYMBOL	PARAMETER	CONDITIONS	MAX	UNIT
I <sub>R</sub>	Reverse Recovery current	$V_R = V_{RRM}$	0.75	mA
V <sub>FM</sub>	Forward Voltage drop	I <sub>F</sub> = 30A, T <sub>J</sub> = 150℃	2.2	V
t <sub>rr</sub>	Reverse Recovery time	$I_F = 1 \text{ A}$ ; -di/dt = 100 A/ $\mu$ s; $V_R = 30 \text{ V}$ ; $T_{VJ} = 25^{\circ}\text{C}$	60	ns

#### **PACKAGE OUTLINE**

Dimensions in mm (1mm = 0.0394")



#### SOT-227 Package Outline

DIM	MILLIMETER		INCHES	
	MIN	MAX	MIN	MAX
A	31.40	31.60	1.236	1.244
В	7.70	8.10	0.303	0.319
C	4.20	4.40	0.165	0.173
D	4.20	4.40	0.165	0.173
E	4.10	4.30	0.161	0.169
F	14.90	15.10	0.587	0.594
G	30.10	30.20	1.165	1.189
Н	38.00	38.30	1.496	1.507
1	23.80	24.20	0.937	0.953
J	12.20	12.70	0.480	0.500
K	9.40	9.60	0.370	0.378
L	0.75	0.85	0.030	0.033
M	1240	12.60	0.488	0.496
N	24.50	25.40	0.964	1.000
0	1.90	2.10	0.075	0.083
P	3.10	3.20	0.122	0.126
Q	26.60	27.00	1.063	1.079
R	3.80	4.20	0.150	0.165
S	5.10	5.40	0.205	0.213

## **STTA9012TV2**



## **Ultrafast High Voltage Diode**

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